•		9 .			
Docket No.:		•			
	DECL.	ARATION AND PO	WER OF AT	TORNEY	
As a below named inver	ntor, I hereby decl	are that:			
My residence, post offic	e and citizenship	are as stated below next to my	name,		
		eventor (if only one name is list med and for which a patent is			
SEMICONDUCTOR	PACKAGE A	ND FABRICATING ME	THOD THERE	OF	
					, th
specification of which					· ·
[X] is attached hereto	[] was filed amended on	on as	Application Seria (if applicabl	l No	and was
I hereby state that I have any amendment referred	reviewed and un to above.	derstand the contents of the ab	ove identified spec	cification, including	the claims, as amended b
Federal Regulations, Sec			•	-	,
application(s) for patent	or inventor's cer	sional application benefits un tificate, or provisional applicate, or provisional application(s)	tion(s) listed belo	w and have also ide	ntified below any foreig
Prior Foreign Applicat	ior Foreign Application(s) or U.S. Provisional Application(s): Priority Claimed				
Number	Country	Day/Month/Year	Yes	No	
7/45/1999	Korea	09/03/1999	х		
pet.		•			
				-	
I hereby claim the henefi	t under Title 35. I	United States Code, Section 12	0 of any United St	ates application(s) li	sted below and, insofar a

the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, Section 112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, Section 1.56(a) which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

Prior U. S. Application(s):

Serial No.

Filing Date

Status: Patented, Pending, Abandoned

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

I hereby appoint the following attorney(s) and/or agent(s):Daniel Y.J. Kim, Registration No. 36,186 and Mark L. Fleshner, Registration No. 34,596: Mark G. Toohey, Registration No. 35,392; Carl R. Wesolowski, Registration No. 40,372, John C. Eisenhart, Registration No. 38,128, Rene A. Vasquez, Registration No. 36,647, all of

The Law Offices of FLESHNER & KIM P. O. Box 221200 Chantilly, Virginia 20153-1200

with full power of substitution and revocation, to prosecute this application and to transact all business in the Patent and Trademark Office connected therewith, and all future correspondence should be addressed to them.

Full name of sole or first inventor: Sun-Dong KIM
Inventor's signature: Sun Dong Kim Date: 08/12/99
Residence: Choongcheongbuk-Do, Korea
Citizenship: Republic of Korea
Sewon 3rd Apt. 106-1106, 1510, Kakyung-Dong, Hungduk-Ku, Rost Office Address: Cheongju, Choongcheongbuk-Do, Korea
######################################
Full name of joint inventor(s):
lhventor's signature: Date:
Residence:
Citizenship:
Post Office Address:
;;;;;;;;;;;;;;;;;;;;;;;;;;;;;;;;;;;;;;
Eull name of joint inventor(s):
hventor's signature: Date:
Residence:
Citizenship:
Post Office Address: